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## Inclosure Material:

Metal

**Overall Length:** 

1.125 inches

Mounting Facility Quantity:

1

# Internal Configuration:

Junction contact

## Mounting Method:

Threaded stud

### **Features Provided:**

Hermetically sealed case

## **Overall Width Across Flats:**

Between 1.031 inches and 1.062 inches

## Thread Size:

0.500 inches

## Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

10.0 off-state voltage, peak and 400.0 off-state voltage, rms total and 5.0 gate voltage, dc

### **Current Rating Per Characteristic:**

2.00 amperes forward current, total rms of standard range and 50.00 amperes forward current, total rms megahertz

### Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npnp

### Test Data Document:

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 uninsulated wire lead w/terminal lug

#### **Specification Data:**

81349-mil-prf-19500 government specification

#### Shelf Life:

N/a

- Unit Of Measure:
- --
- **Demilitarization:**

No

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**Fiig:** A110a0

Mil-std (military Standard):

Mil-prf-19500 spec.